

Features

- $BV_{CEO} > -20V$
- $I_C = -2A$ High Continuous Collector Current
- $R_{CE(SAT)} = 100m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage $V_{CE(SAT)} < -150mV @ -1A$
- Sidewall Tin Plating for Wettable Flanks in AOI
- P_D up to 2.47W for Power Demanding Applications
- Low Profile 0.6mm High Package for Thin Applications
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

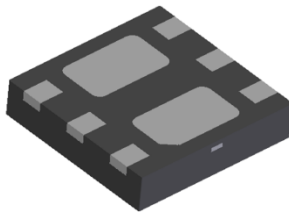
Mechanical Data

- Case: U-DFN2020-6 (SWP) (Type A) with Sidewall Plating (SWP)
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin, Solderable per MIL-STD-202, Method 208
- Weight: 0.0065 grams (Approximate)

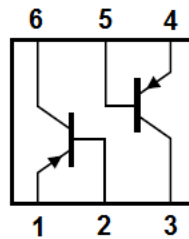
Application

- Matrix LED Lighting
- Power Management

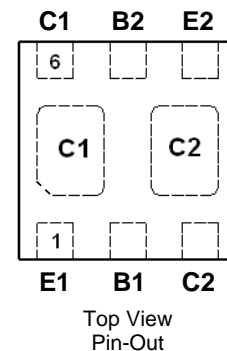
U-DFN2020-6 (SWP) (Type A)



Bottom View



Device Symbol



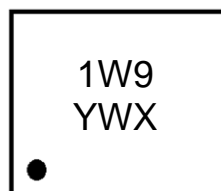
Top View
Pin-Out

Ordering Information (Notes 4 & 5)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTP56020FDBQ-7	1W9	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



1W9 = Product Type Marking Code
 Y = Year: 0~9
 W = Week: A~Z: 1~26 week;
 a~z: 27~52 week; z represents
 52 and 53 week
 X = A~Z: Internal Code

Absolute Maximum Ratings – Q1 & Q2 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-20	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-2	A
Peak Pulse Collector Current	I _{CM}	-3	A
Base Current	I _B	-300	mA
Peak Base Current	I _{BM}	-1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

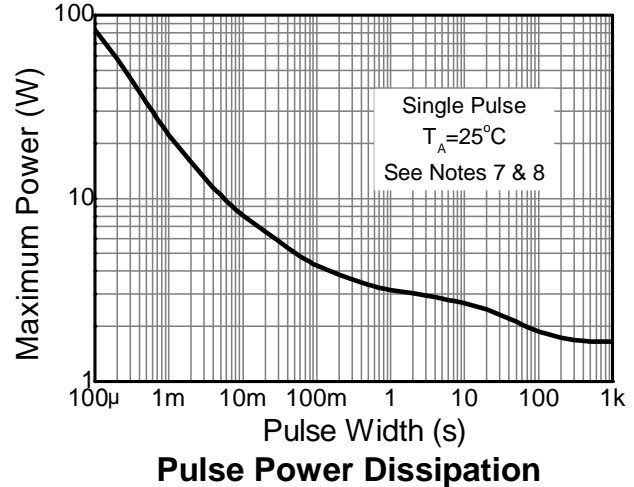
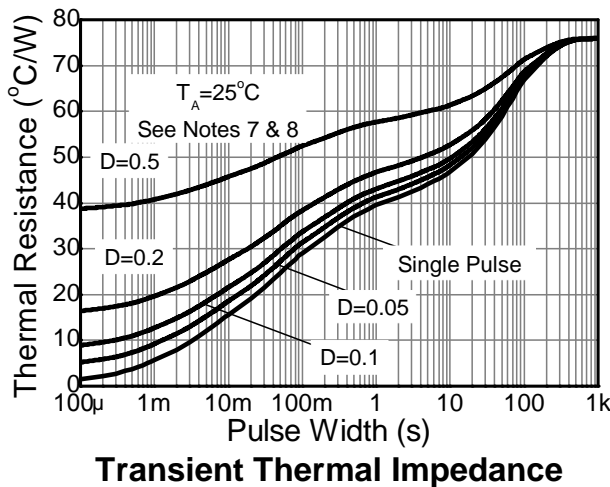
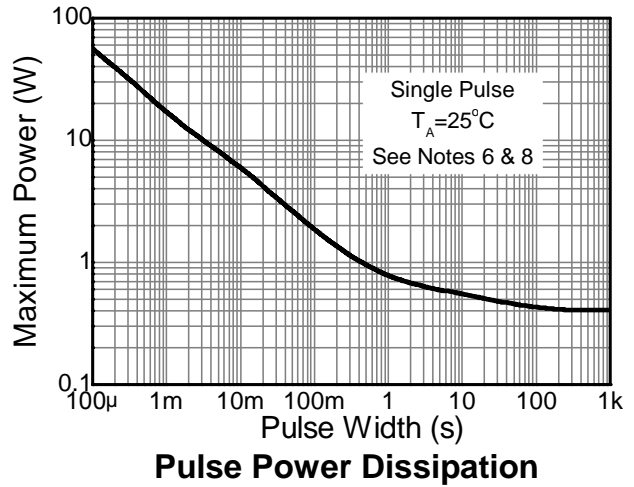
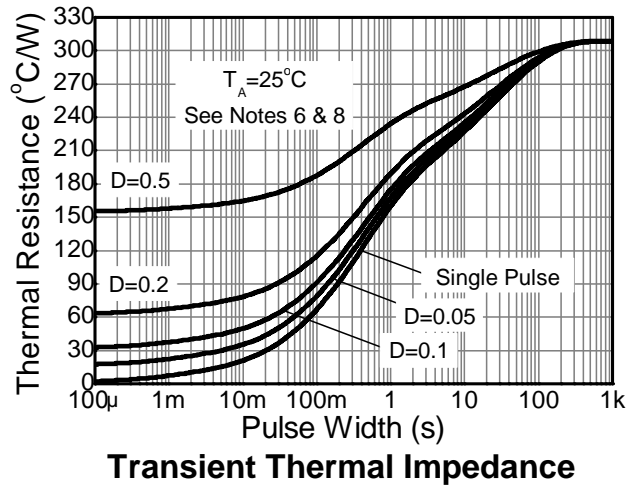
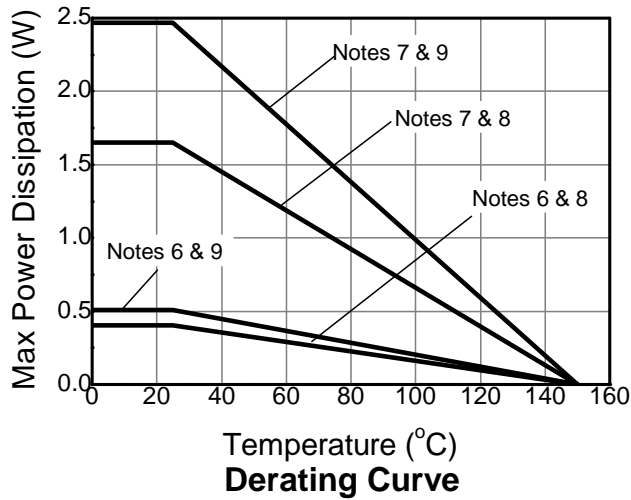
Characteristic	Symbol	Value	Unit
Power Dissipation	(Notes 6 & 8)	405	mW
	(Notes 6 & 9)	510	
	(Notes 7 & 8)	1650	
	(Notes 7 & 9)	2470	
Thermal Resistance, Junction to Ambient	(Notes 6 & 8)	308	°C/W
	(Notes 6 & 9)	245	
	(Notes 7 & 8)	76	
	(Notes 7 & 9)	51	
Thermal Resistance, Junction to Lead	(Note 10) R _{θJL}	18	°C/W
Operating and Storage Temperature Range	— T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	C

- Notes:
6. For a device mounted with the exposed collector pads on minimum recommended pad layout that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 7. Same as note (6), except the device is mounted with the collector pad on 28mm x 28mm (8cm²) 2oz copper.
 8. For a dual device with one active die.
 9. For dual device with 2 active die running at equal power.
 10. Thermal resistance from junction to solder-point (on the exposed collector pads).
 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

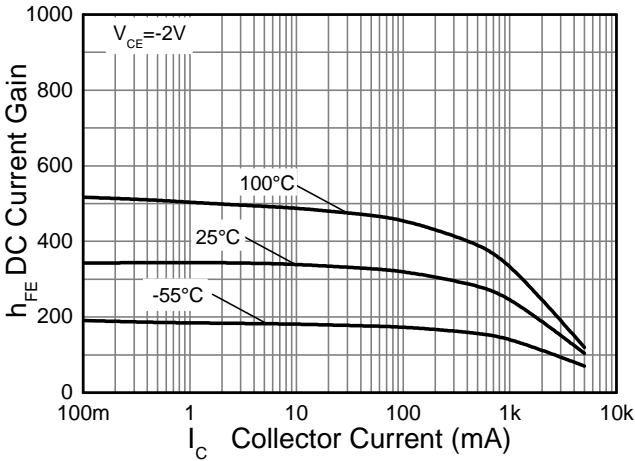


Electrical Characteristics – Q1 & Q2 (@T_A = +25°C, unless otherwise specified.)

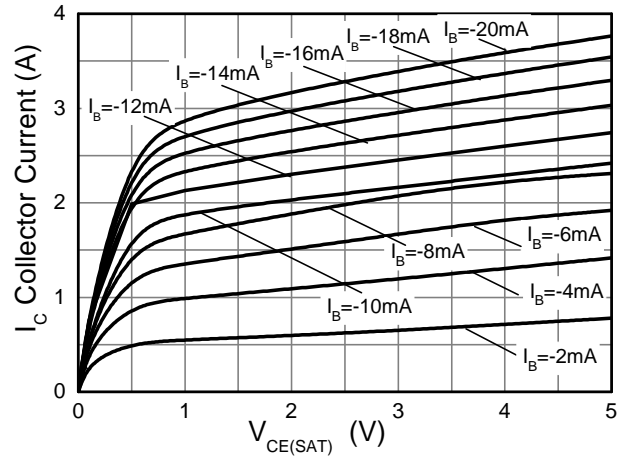
Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	BV _{CB0}	-20	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 12)	BV _{CEO}	-20	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CBO}	—	—	-100	nA	V _{CB} = -16V, I _E = 0
		—	—	-50	μA	V _{CB} = -16V, I _E = 0, T _A = +150°C
Emitter-Base Cutoff Current	I _{EBO}	—	—	-100	nA	V _{EB} = -5.6V, I _C = 0
DC Current Gain (Note 12)	h _{FE}	250	—	—	—	V _{CE} = -2V, I _C = -100mA
		210	—	—		V _{CE} = -2V, I _C = -500mA
		170	—	—		V _{CE} = -2V, I _C = -700mA
		160	—	—		V _{CE} = -2V, I _C = -1A
		100	—	—		V _{CE} = -2V, I _C = -2A
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(SAT)}	—	—	-110	mV	I _C = -500mA, I _B = -50mA
		—	—	-220		I _C = -1A, I _B = -50mA
		—	—	-200		I _C = -0.7A, I _B = -7mA
		—	—	-390		I _C = -2A, I _B = -200mA
Equivalent On-Resistance (Note 12)	R _{CE(SAT)}	—	—	220	mΩ	I _E = -1A, I _B = -50mA
Base-Emitter Saturation Voltage (Note 12)	V _{BE(SAT)}	—	—	-1	V	I _C = -0.5A, I _B = -50mA
		—	—	-1.1		I _C = -1A, I _B = -50mA
		—	—	-1.25		I _C = -2A, I _B = -200mA
Base-Emitter Turn-on Voltage (Note 12)	V _{BE(ON)}	—	—	-0.9	V	V _{CE} = -2V, I _C = -0.5A
Turn-On Time	t _{ON}	—	60	—	ns	I _C = -1A, I _{B1} = -I _{B2} = 50mA; T _A = +25°C
Delay Time	t _D	—	10	—	ns	
Rise Time	t _R	—	50	—	ns	

Note: 12. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

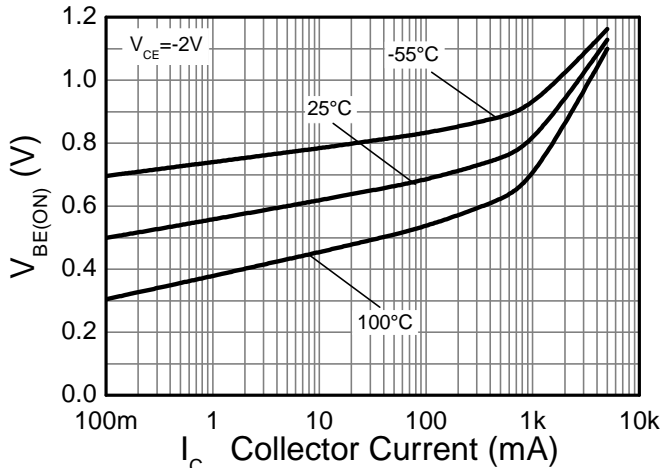
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



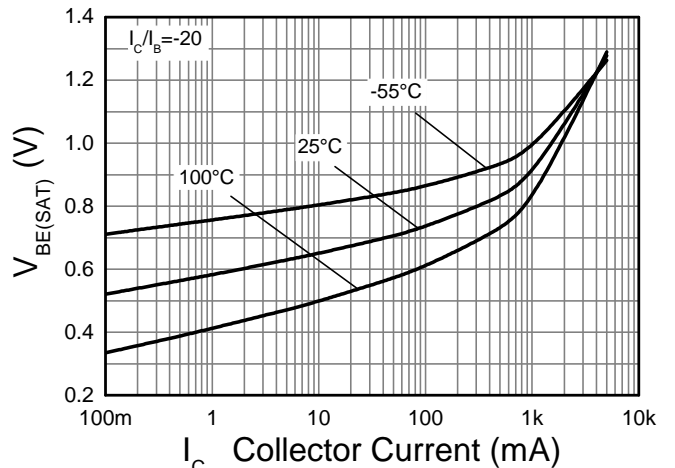
h_{FE} v Collector Current



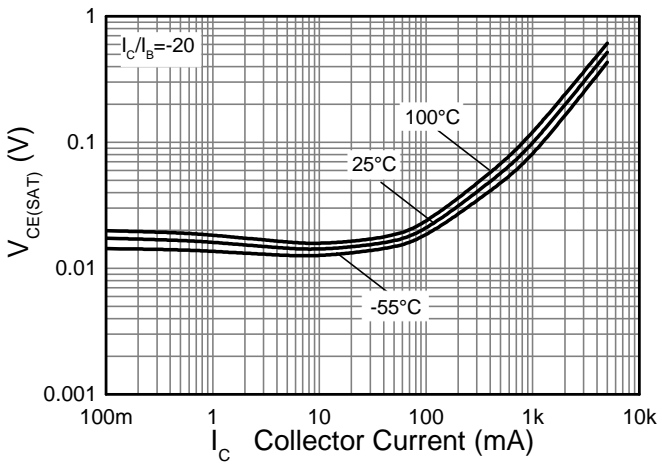
Collector Current v $V_{CE(SAT)}$



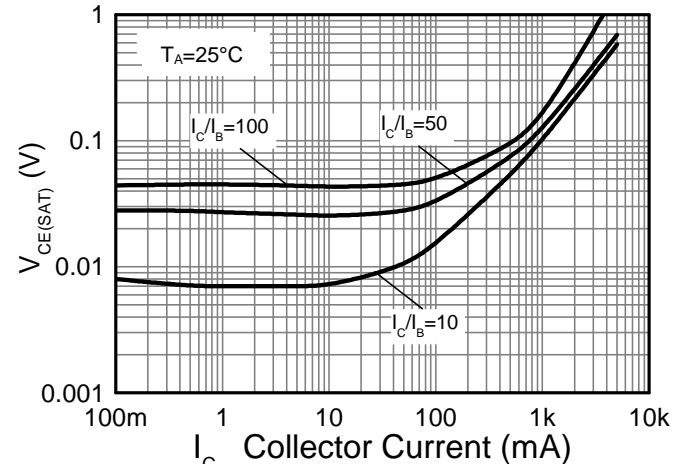
$V_{BE(ON)}$ v Collector Current



$V_{BE(SAT)}$ v Collector Current



$V_{CE(SAT)}$ v Collector Current

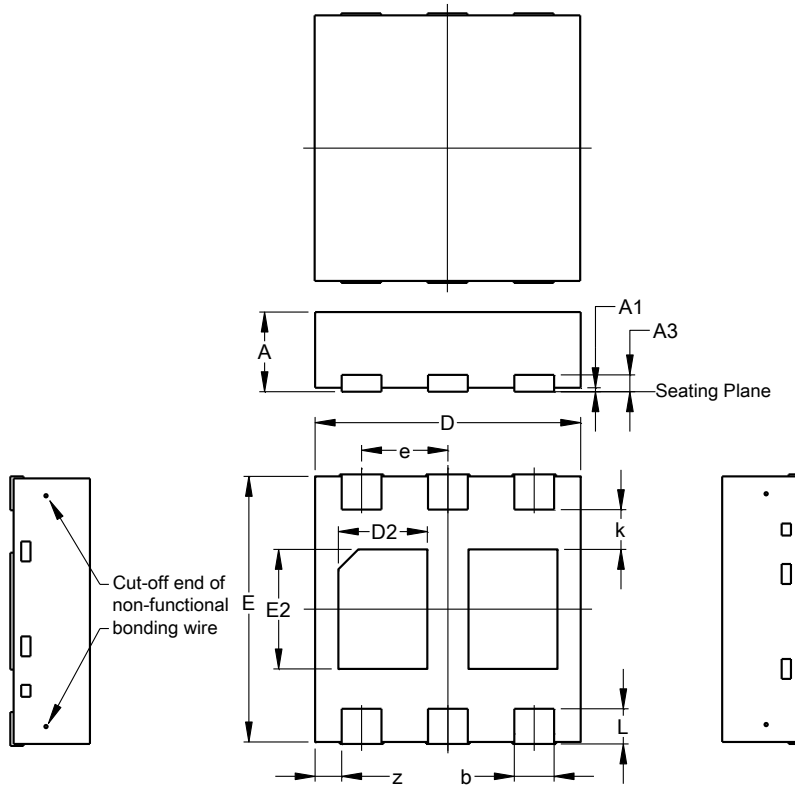


$V_{CE(SAT)}$ v Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN2020-6 (SWP) (Type A)

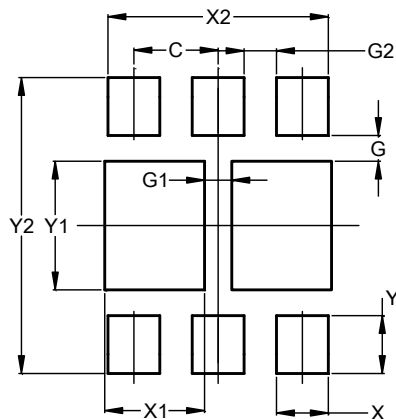


U-DFN2020-6 (SWP) (Type A)			
Dim	Min	Max	Typ
A	0.55	0.65	0.60
A1	0.00	0.05	0.03
A3	--	--	0.127
b	0.25	0.35	0.30
D	1.95	2.05	2.00
D2	0.57	0.77	0.67
E	1.95	2.05	2.00
E2	0.80	1.00	0.90
e	0.65BSC		
k	0.30BSC		
L	0.22	0.32	0.27
z	0.20BSC		
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN2020-6 (SWP) (Type A)



Dimensions	Value (in mm)
C	0.650
G	0.200
G1	0.210
G2	0.250
X	0.400
X1	0.770
X2	1.700
Y	0.450
Y1	1.000
Y2	2.300

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